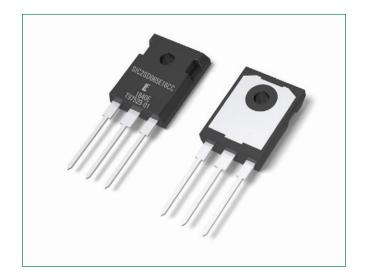


LSIC2SD065E16CCA 650 V, 16 A SiC Schottky Barrier Diode









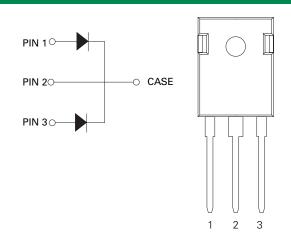
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C. maximum operating junction temperature
- · Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-247-3L



Applications

- · Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- · Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating



Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V
DC Blocking Voltage	V_{R}	T _J = 25 °C	650	V
		T _C = 25 °C	23 / 46	
Continuous Forward Current (Per Leg/Component)	I _F	T _C = 135 °C	10.7 / 21.4	А
		T _C = 150 °C	8 / 16	
Non-Repetitive Forward Surge Current Per Leg)	I _{FSM}	$T_{\rm C}$ = 25 °C, $t_{\rm p}$ = 10 ms, Half sine pulse	40	А
Power Dissipation (Per Leg/Component)	P _{Tot}	T _C = 25 °C	88 / 176	W
		T _C = 110 °C	38 / 76	VV
Operating Junction Temperature	T _J	-	-55 to 175	°C
Storage Temperature	T _{STG}	-	-55 to 150	°C
Soldering Temperature	T _{sold}	-	260	°C

GEN2 SiC Schottky Diode LSIC2SD065E16CCA, 650 V, 16 A, T0-247-3L

Electrical Characteristics (T_J = 25 °C unless otherwise specified)

Characteristics	Symbol	Conditions	Value			Unit
Characteristics			Min.	Тур.	Max.	Onit
Forward Voltage		I _F = 8 A, T _J = 25 °C	-	1.5	1.8	V
	V _F	I _F = 8 A, T _J = 175 °C	-	1.85	-	
Reverse Current	I _R	$V_R = 650 \text{ V, } T_J = 25 ^{\circ}\text{C}$	-	<1	50	μΑ
		V _R = 650 V, T _J = 175 °C	-	15	-	
Total Capacitance	С	$V_R = 1 \text{ V, f} = 1 \text{ MHz}$	-	415	-	pF
		$V_{R} = 200 \text{ V, f} = 1 \text{ MHz}$	-	56	-	
		V _R = 400 V, f = 1 MHz	-	41	-	
Total Capacitive Charge	O _c	V _R = 800 V, Q _e =∫ C(V)dV 0	-	29	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance (Per Leg/Component)	R _{e.ic}	1.7 / 0.85	°C/W

Figure 1: Typical Foward Characteristics

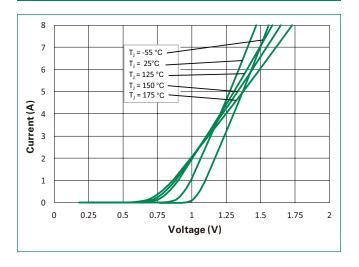


Figure 2: Typical Reverse Characteristics

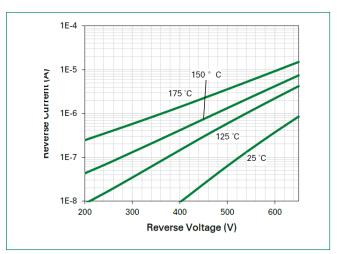




Figure 3: Power Derating

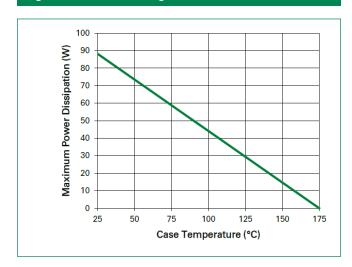


Figure 4: Current Derating

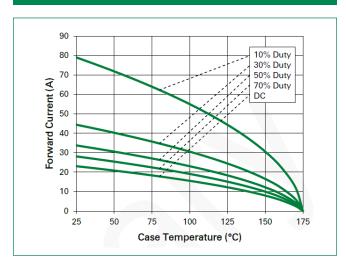


Figure 5: Capacitance vs. Reverse Voltage

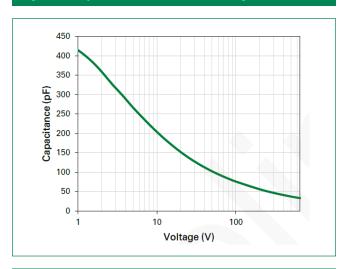


Figure 6: Capacitive Charge vs. Reverse Voltage

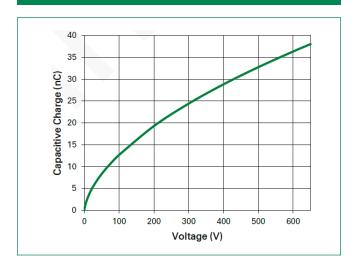


Figure 7: Stored Energy vs. Reverse Voltage

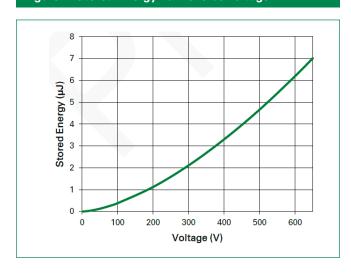
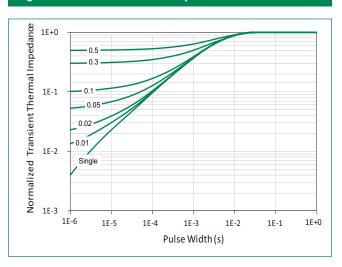
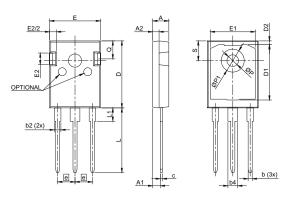


Figure 8: Transient Thermal Impedance



GEN2 SiC Schottky Diode LSIC2SD065E16CCA, 650 V, 16 A, TO-247-3L

Package Dimensions TO-247-3L



Recommended Hole Pattern Layout



- Notes:

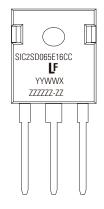
 1. Dimensions are in millimeters

 2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.

 3.0P to have a maximum draft angle of 1.5" to the top of the part with a maximum hole diameter of 0.154"

Symbol	Millimeters				
Cymbol	Min	Nom	Max		
Α	4.80	5.03	5.20		
A1	2.25	2.38	2.54		
A2	1.85	1.98	2.11		
b	0.99	-	1.40		
b2	1.65	-	2.39		
b4	2.59	-	3.43		
С	0.38	0.64	0.89		
D	20.80	20.96	21.34		
D1	13.50	-	-		
D2	0.51	1.19	1.35		
е	5.44 BSC				
E	15.75	15.90	16.13		
E1	13.06	14.02	14.15		
E2	4.19	4.32	4.83		
L	19.81	20.19	20.57		
L1	3.81	4.19	4.45		
øΡ	3.55	3.61	3.66		
øP1	7.06	7.19	7.32		
Q	5.49	5.61	6.20		
s	6.05	6.17	6.30		

Part Numbering and Marking System



SIC	= SiC
2	= Gen2
SD	= Schottky Diode
065	= Voltage Rating (650 V)
_	

= T0-247-3L Ε = Current Rating (16 A) 16

CC= Common Cathode = Year ΥY

WW

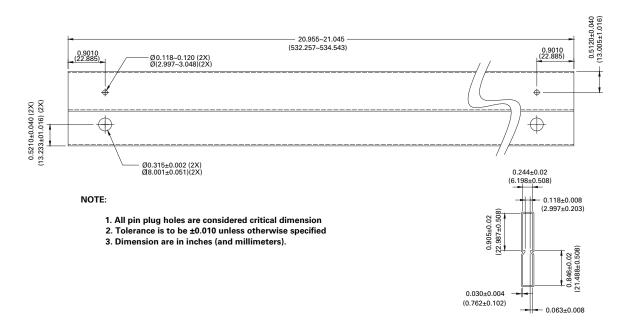
Χ = Trace Code (Any Letter) ZZZZZZ-ZZ = Lot Number

Packing Options

Part Number		Marking	Packing Mode M.O.C	
ĺ	LSIC2SD065E16CCA	SIC2SD065E16CC	Tube (30pcs)	450

GEN2 SiC Schottky Diode LSIC2SD065E16CCA, 650 V, 16 A, TO-247-3L

Packing Specification TO-247-3L



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